Reference only

Gate Driver optimized for Infineon Technologies AG

IGBT Power Module FF900R12ME7_B11

FF900R17ME7_B11









Supported by Infineon Technologies AG



Reference only



Gate Drivers optimized for Infineon Technologies AG FF900R12ME7_B11 / FF900R17ME7_B11

Appliance



FF900R12ME7_B11 FF900R17ME7_B11

Features

- Large Output Power
- Peak Current (43A)
- Supports multi-parallel drive

Specification

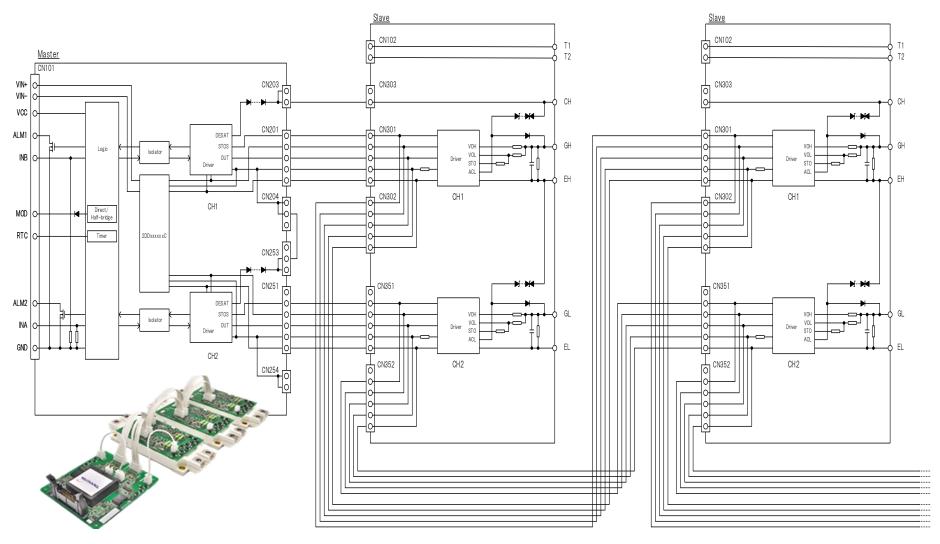
Item	Development value
Output voltage	+15V / -10V
Short protection	DESAT + Soft turn off *1
Number that can be driven in parallel at 3kHz (FF900R12ME7_B11)	3
Number that can be driven in parallel at 3kHz (FF900R17ME7_B11)	5
Park current	43A
Withstand voltage	5kV
Partial discharge extinction voltage	1.768kV peak (min)
CMTI	70kV/us
Clearance / creepage (Pri-Sec)	14mm / 16mm
Clearance / creepage (Sec-Sec)	7mm / 12mm





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Connection diagram in parallel drive



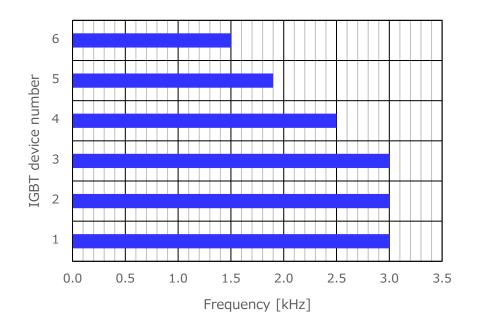
Reference only



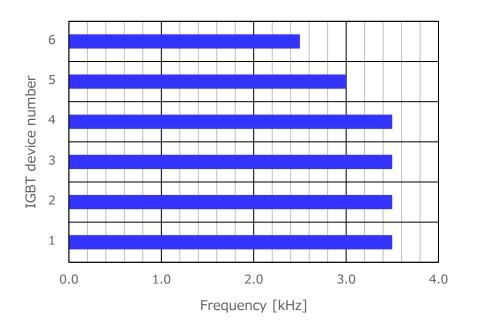
Gate Drivers optimized for Infineon Technologies AG FF900R12ME7_B11 / FF900R17ME7_B11

Frequency vs Gate driver parallel number (+15V / -10V)

• FF900R12ME7_B11



· FF900R17ME7_B11



^{*}This data is under development.

The content of this document is subject to change without prior notice.

Appendix) Information & Contact



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 3D data to design!
- One-click to purchase from the check stock!

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